

Vishay Semiconductors

Small Signal Fast Switching Diodes



FEATURES

- Silicon epitaxial planar diode
- AEC-Q101 qualified
- Material categorization:
 For definitions of compliance please see www.vishay.com/doc?99912

Ph

RoHS

COMPLIANT HALOGEN FREE

APPLICATIONS

· Extreme fast switches

MECHANICAL DATA

Case: DO-35

Weight: approx. 125 mg
Cathode band color: black
Packaging codes/options:

TR/10K per 13" reel (52 mm tape), 50K/box TAP/10K per ammopack (52 mm tape), 50K/box

PARTS TABLE						
PART	ORDERING CODE	TYPE MARKING	INTERNAL CONSTRUCTION	REMARKS		
1N4154	1N4154TR or 1N4154TAP	1N4154	Single diode	Tape and reel/ammopack		

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
Repetitive peak reverse voltage		V _{RRM}	35	V		
Reverse voltage		V _R	25	V		
Peak forward surge current	t _p = 1 μs	I _{FSM}	2	А		
Repetitive peak forward current		I _{FRM}	500	mA		
Forward continuous current		I _F	300	mA		
Average forward current	V _R = 0	I _{F(AV)}	150	mA		
Davier discipation	I = 4 mm, T _L = 45 °C	P _{tot}	440	mW		
Power dissipation	I = 4 mm, T _L ≤ 25 °C	P _{tot}	500	mW		

THERMAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
Thermal resistance junction to ambient air	I = 4 mm, T _L = constant	R _{thJA}	350	K/W		
Junction temperature		Tj	175	°C		
Storage temperature range		T _{stg}	- 65 to + 175	°C		



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ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I _F = 30 mA	V _F		0.88	1	V
Reverse current	V _R = 25 V	I _R		9	100	nA
neverse current	V _R = 25 V, T _j = 150 °C	I _R			100	μA
Breakdown voltage	$I_R = 5 \mu A, t_p/T = 0.01,$ $t_p = 0.3 \text{ ms}$	V _(BR)	35			V
Diode capacitance	$V_R = 0 \text{ V, f} = 1 \text{ MHz,}$ $V_{HF} = 50 \text{ mV}$	C _D			4	pF
Reverse recovery time	$I_F = I_R = 10 \text{ mA},$ $I_R = 1 \text{ mA}$	+			4	- ns
neverse recovery time	$I_F = 10 \text{ mA}, V_R = 6 \text{ V},$ $I_R = 0.1 \text{ x } I_R, R_L = 100 \Omega$	t _{rr}			2	

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

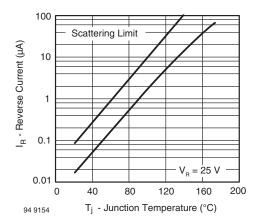


Fig. 1 - Reverse Current vs. Junction Temperature

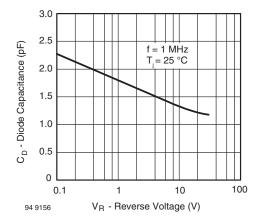


Fig. 3 - Diode Capacitance vs. Reverse Voltage

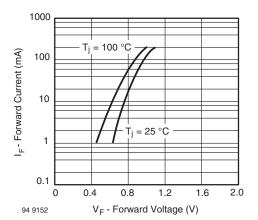
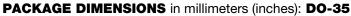
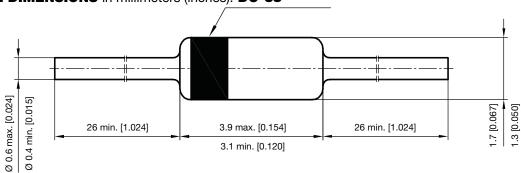


Fig. 2 - Forward Current vs. Forward Voltage

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<u>1N4154TR</u> <u>1N4154TAP</u>